Triacs BTA140 series

#### **GENERAL DESCRIPTION**

# Glass passivated triacs in a plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

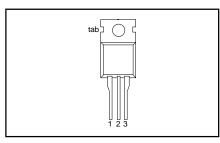
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
$V_{DRM}$	BTA140- Repetitive peak off-state	<b>500</b> 500	<b>600</b> 600	<b>800</b> 800	V
I <sub>T(RMS)</sub> I <sub>TSM</sub>	voltages RMS on-state current Non-repetitive peak on-state current	25 180	25 180	25 180	A A

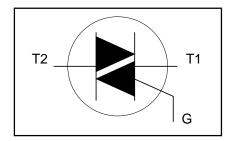
# **PINNING - TO220AB**

PIN	DESCRIPTION		
1	main terminal 1		
2	main terminal 2		
3	gate		
tab	main terminal 2		

# **PIN CONFIGURATION**



# **SYMBOL**



# **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
$V_{DRM}$	Repetitive peak off-state voltages		-	<b>-500</b> 500 <sup>1</sup>	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	V
I <sub>T(RMS)</sub>	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 91 ^{\circ}\text{C}$ full sine wave; $T_{j} = 125 ^{\circ}\text{C}$ prior to surge; with reapplied $V_{DRM(max)}$	-		25		А
		t = 20 ms t = 16.7 ms	-		180 200		Α
l²t dl <sub>⊤</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after	t = 10.7  ms t = 10  ms $I_{TM} = 30 \text{ A}; I_{G} = 0.2 \text{ A};$ $dI_{G}/dt = 0.2 \text{ A}/\mu\text{s}$	-		160		A A <sup>2</sup> s
	triggering	T2+ G+ T2+ G- T2- G- T2- G+	- - -		50 50 50		A/μs A/μs A/μs
I <sub>GM</sub> V <sub>GM</sub> P <sub>GM</sub>	Peak gate current Peak gate voltage Peak gate power	12- 0+	- - -		10 2 5 5		A/μs A V W
P <sub>G(AV)</sub> T <sub>stg</sub> T <sub>j</sub>	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- -40 -		0.5 150 125		Ç Ç

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

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# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance	full cycle half cycle in free air		- - 60	1.0 1.4 -	K/W K/W K/W
1	junction to ambient					

# STATIC CHARACTERISTICS

 $T_j = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$					
			+ G+	-	6	35	mΑ
		I	+ G-	-	10	35	mA
			- G-	-	11	35	mĄ
			- G+	-	23	70	mA
I <sub>L</sub>	Latching current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$			0	40	Л
			+ G+ + G-	-	8 30	40	mA mA
			- G-	-	30 18	60 40	mA
			- G+	_	15	60	mA
I <sub>H</sub>	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$	Ŭ.		10		1117 (
- n		T2+	+	-	7	30	mΑ
		T2-	-	-	12	30	mΑ
$V_T$	On-state voltage	$I_{T} = 30 \text{ A}$		-	1.2	1.55	V
$V_{GT}$	Gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$			0.7	1.5	V
1.	<b></b>	$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_i = 125 ^{\circ}\text{C}$		0.25	0.4	-	٧.
I <sub>D</sub>	Off-state leakage current	$V_D = V_{DRM(max)}$ ; $T_j = 125 °C$		-	0.1	0.5	mA

# **DYNAMIC CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	100	300	-	V/μs
dV <sub>com</sub> /dt	off-state voltage Critical rate of change of commutating voltage	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}$ ; $T_j = 95 \text{ °C}$ ; $I_{T(RMS)} = 25 \text{ A}$ ; $dI_{com}/dt = 9 \text{ A/ms}$ ; gate open circuit	-	10	-	V/μs
t <sub>gt</sub>	Gate controlled turn-on time	$I_{TM} = 30 \text{ A}$ ; $V_D = V_{DRM(max)}$ ; $I_G = 0.1 \text{ A}$ ; $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

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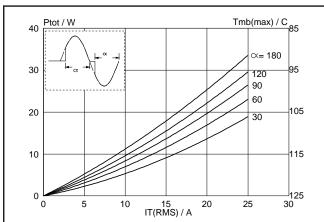


Fig.1. Maximum on-state dissipation, Ptot, versus rms on-state current,  $I_{T(RMS)}$ , where  $\alpha = conduction$  angle.

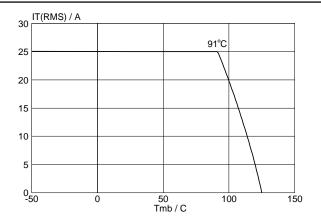


Fig.4. Maximum permissible rms current  $I_{T(RMS)}$ , versus mounting base temperature  $T_{mb}$ .

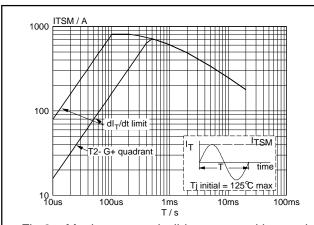


Fig.2. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_n \le 20$ ms.

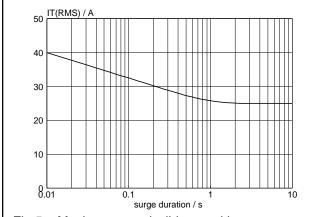


Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{mb} \le 91$ °C.

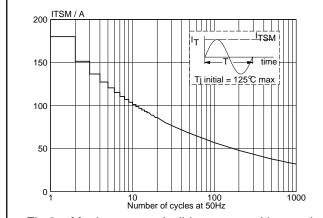
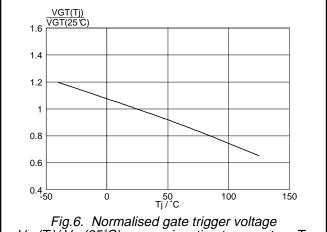


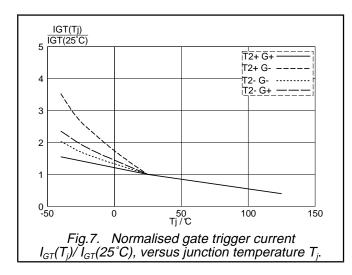
Fig.3. Maximum permissible non-repetitive peak on-state current I<sub>TSM</sub>, versus number of cycles, for sinusoidal currents, f = 50 Hz.

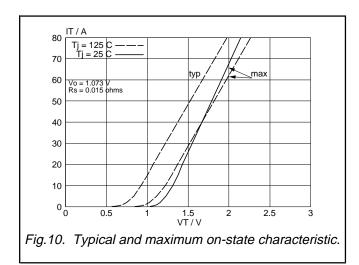


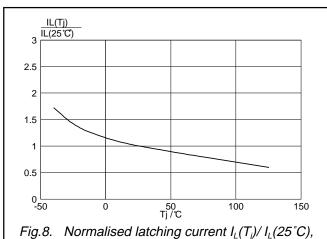
 $V_{GT}(T_i)/V_{GT}(25^{\circ}C)$ , versus junction temperature  $T_i$ .

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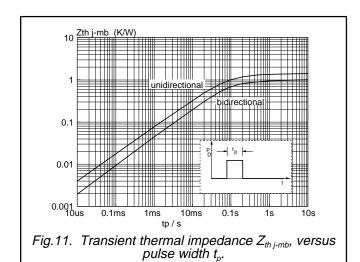
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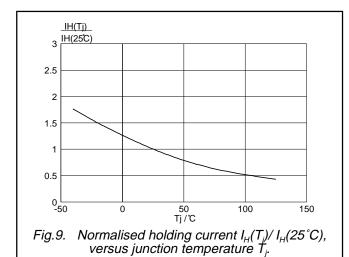






versus junction temperature T





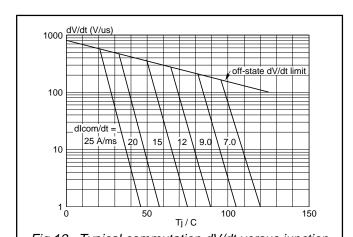
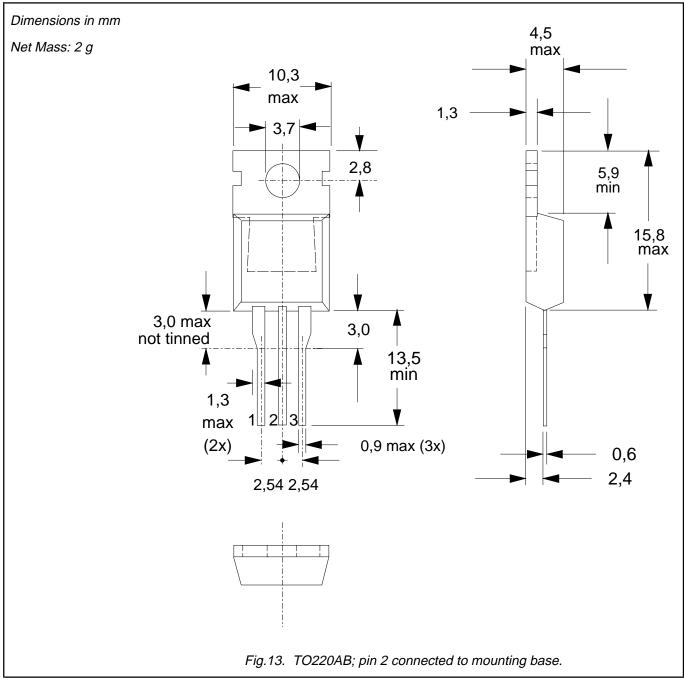


Fig.12. Typical commutation dV/dt versus junction temperature, parameter commutation dl<sub>T</sub>/dt. The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation dl<sub>T</sub>/dt.

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# **MECHANICAL DATA**



- Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
   Epoxy meets UL94 V0 at 1/8".

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#### **DEFINITIONS**

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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